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CERTIFICATE OF TRANSMISSION**December 20, 2002**

Atty Docket No.:	TKHR4540
Appl. No.:	09/467,675
Filing Date:	December, 21, 1999
Pages:	Cover + 10

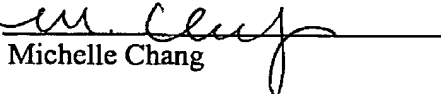
BY FACSIMILE ONLY

Fax No.: 703-872-9319
Attention: Examiner NADAV, ORI
Group Unit: 2811
From: Jiawei Huang, Reg. No. 43,330
MESSAGE: Enclosed is an Amendment in 10 pages.

FAX RECEIVED**DEC 20 2002****TECHNOLOGY CENTER 2800**

Sir:

I hereby certify that this correspondence is being facsimile transmitted to the Patent and Trademark Office on **December 20, 2002** at the above indicated fax number.

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Atty D cket No.: TKHR4540

Serial No.: 09/467,675

#17/C
(N.E.)
1-13-03
L. Spruell**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of :
Application No. : 09/467,675
Filed : December 21, 1999
For : Structure For ESD Protection With Single Crystal Silicon Sided Junction
Applicant : Liou et al.
Examiner : Ori Nadav
Art Unit : 2811

FAX RECEIVED**AMENDMENT AND RESPONSE TO OFFICE ACTION**

DEC 20 2002

Assistant Commissioner of Patents and Trademarks
Washington, DC 20231

TECHNOLOGY CENTER 2800

Sir:

In response to the Office Action dated September 30, 2002, please consider the following remarks.

In The Claims:

Please substitute the following clean text claims for the pending claims having the same number.

do not
enter
on

1. (Thrice Amended) An ESD protection structure having a single crystal Si-sided diode used to protect an internal circuit, the ESD protection structure electrically connected between an input pad and a node and the internal circuit electrically connected to the node, the ESD protection structure comprising: